

View Online at <https://aerobasegroup.com/nsn/5961-01-077-8571>

Inclosure Material:

Metal all transistor

Overall Length:

0.805 inches all transistor and 0.925 inches all transistor

Overall Width:

1.255 inches all transistor and 1.475 inches all transistor

Mounting Facility Quantity:

1 all transistor

Internal Configuration:

Junction contact all transistor

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-117 all transistor

Internal Junction Configuration:

Npn all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Threaded stud all transistor

Features Provided:

Hermetically sealed case

Thread Size:

0.164 inches all transistor

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-emitter, base open all transistor

Current Rating Per Characteristic:

4.00 amperes source cutoff current all transistor

Thread Series Designator:

Unc all transistor

Terminal Type And Quantity:

4 ribbon all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

A110a0